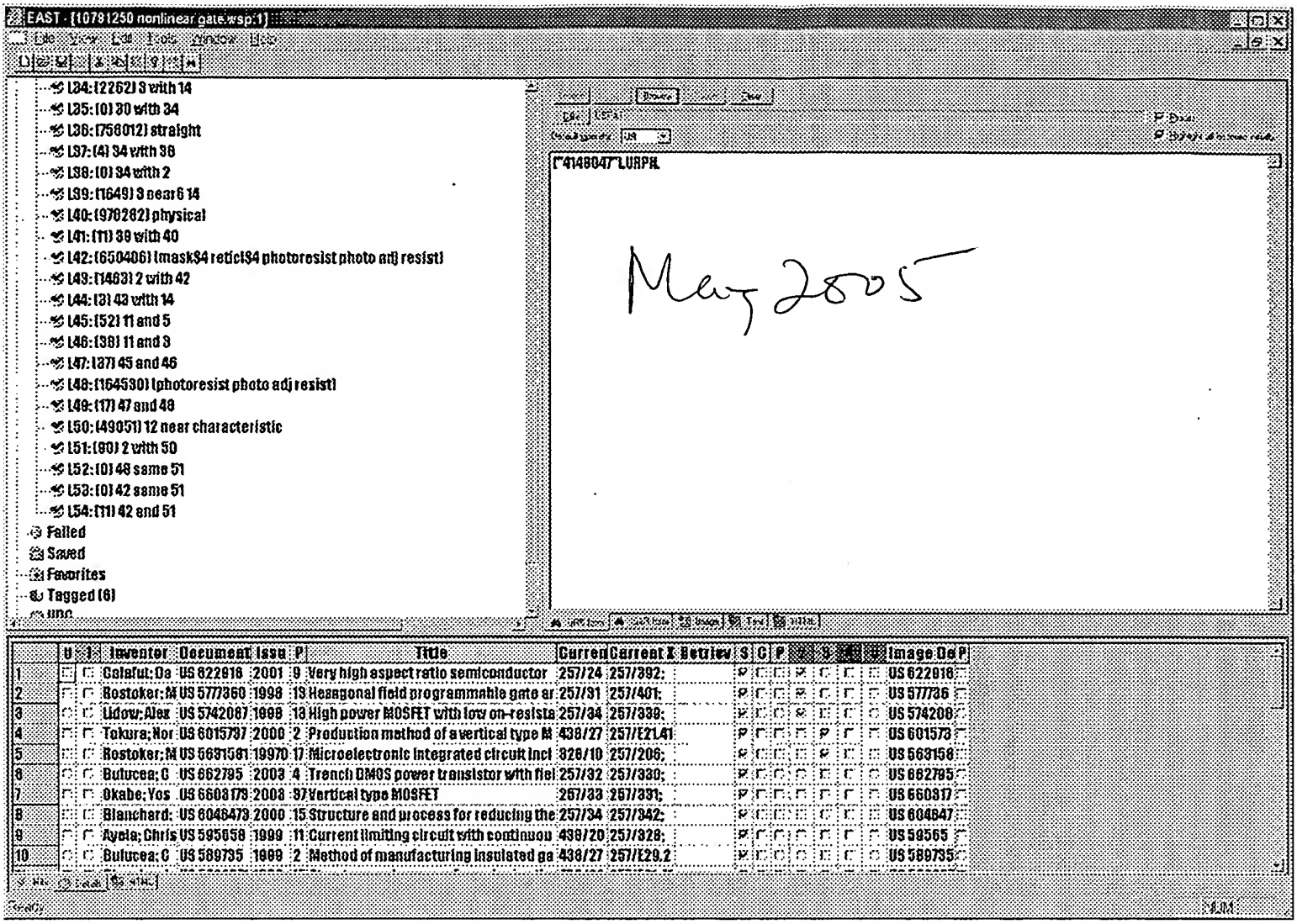
EAST - [10781250 nonlinear gate.wsp:1]
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L34: (2262) 3 with 14
L35: (0) 30 with 34
L36: (758012) straight
L37: (4) 34 with 36
L38: (0) 34 with 2
L39: (1649) 3 near6 14
L40: (978282) physical
L41: (11) 39 with 40
L42: (650406) (mask$4 reticl$4 photoresist photo adj resist)
L43: (14631) 2 with 42
L44: (3) 43 with 14
L45: (52) 11 and 5
L46: (38) 11 and 3
L47: (37) 45 and 46
L48: (1645301) (photoresist photo adj resist)
L49: (17) 47 and 48
L50: (49051) 12 near characteristic
L51: (90) 2 with 50
L52: (0) 48 same 51
L53: (0) 42 same 51
L54: (11) 42 and 51
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